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APPLICANT: Holger RUCKER et al.

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UNITED STATES PATENT DOCUMENTS

EXAM. INITIAL		DOCUMENT NUMBER	DATE	INVENTOR/ASSIGNEE	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	US	2002/0117733	Aug. 29, 2002	Michael Farjami, Esq.			
	US	6,642,553	Nov. 4, 2003	Juergen Drews et al.			
	US	2003/0189239	Oct. 9, 2003	Alexander Kalnitsky et al.			
	US	5,523,606	Jun. 4, 1996	Toru Yamazaki			
	US	6,492,238	Dec. 10, 2002	David C. Ahlgren et al.			

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES/NO
	EP	0 418 185 A1	Jul. 31, 1990	EP			
	EP	1 128 422 A1	Aug. 29, 2001	EP			
	EP	0 949 665 A2	Apr. 7, 1999	EP			

OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)

	H.J. Osten et al., <i>The Effect of Carbon Incorporation on SiGe Heterobipolar Transistor Performance and Process Margin</i> ; IEEE 1997 O-7803-4100 (pages 32.4.1 - 32.4.4).

/Long Pham/

Examiner (To be assigned)

Date:

10/20/2000